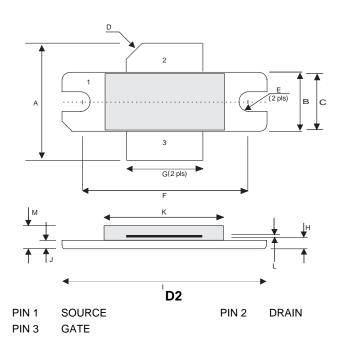


## ROHS COMPLIANT METAL GATE RF SILICON FET

### MECHANICAL DATA



DIM	Millimetres	Tol.	Inches	Tol.
Α	19.43	0.13	0.765	0.005
В	9.78	0.13	0.385	0.005
С	9.40	0.10	0.370	0.004
D	45°	5°	45°	5°
E	1.63R	0.13	0.064R	0.005
F	27.94	0.13	1.100	0.005
G	12.70	0.13	0.500	0.005
Н	1.57	0.13	0.062	0.005
I	34.04	0.13	1.340	0.005
J	1.01	0.13	0.040	0.005
K	19.94	0.25	0.785	0.009
L	0.10	0.25	0.004	0.002
М	4.24	0.25	0.167	0.01

# **GOLD METALLISED** MULTI-PURPOSE SILICON **DMOS RF FET** 150W - 28V - 175MHzSINGLE ENDED

### **FEATURES**

- SUITABLE FOR BROAD BAND APPLICATIONS
- SIMPLE BIAS CIRCUITS
- ULTRA-LOW THERMAL RESISTANCE
- BeO FREE
- LOW C<sub>rss</sub>
- HIGH GAIN 15 dB MINIMUM

## **APPLICATIONS**

 HF/VHF/UHF COMMUNICATIONS from 1 MHz to 200 MHz

## **ABSOLUTE MAXIMUM RATINGS** (T<sub>case</sub> = 25℃ unless otherwise stated)

$P_{D}$	Power Dissipation	438W (219W -A Version)
$BV_DSS$	Drain – Source Breakdown Voltage	70V
$BV_GSS$	Gate – Source Breakdown Voltage	±20V
I <sub>D(sat)</sub>	Drain Current	30A
T <sub>stg</sub>	Storage Temperature	–65 to 150℃
T <sub>i</sub>	Maximum Operating Junction Temperature	200℃

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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# DMD1006-A

## **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25℃ unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
B\/	Drain-Source	V <sub>GS</sub> = 0	I <sub>D</sub> = 100mA	70			V
BV <sub>DSS</sub>	Breakdown Voltage	VGS - 0	1D = 1001114	70			V
1	Zero Gate Voltage	V <sub>DS</sub> = 28V	V <sub>GS</sub> = 0			6	mA
DSS	Drain Current	VDS - 20V				U	ША
I <sub>GSS</sub>	Gate Leakage Current	V <sub>GS</sub> = 20V	V <sub>DS</sub> = 0			1	μΑ
V <sub>GS(th)</sub>	Gate Threshold Voltage*	I <sub>D</sub> = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 <sub>fs</sub>	Forward Transconductance*	V <sub>DS</sub> = 10V	I <sub>D</sub> = 6A	4.8			S
G <sub>PS</sub>	Common Source Power Gain	P <sub>O</sub> = 150W		15			dB
η	Drain Efficiency	V <sub>DS</sub> = 28V	$I_{DQ} = 1.2A$	50			%
VSWR	Load Mismatch Tolerance	f = 175MHz		20:1			_
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 0V$	$V_{GS} = -5V$ $f = 1MHz$			360	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 28V	$V_{GS} = 0$ $f = 1MHz$			180	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	V <sub>DS</sub> = 28V	$V_{GS} = 0$ $f = 1MHz$			15	pF

<sup>\*</sup> Pulse Test: Pulse Duration = 300  $\mu s$ , Duty Cycle  $\leq$  2%

## THERMAL DATA

R <sub>THi-case</sub>	Thermal Resistance Junction – Case	Max. 0.4℃ / W	
,		0.8 ℃ / W -A Version	

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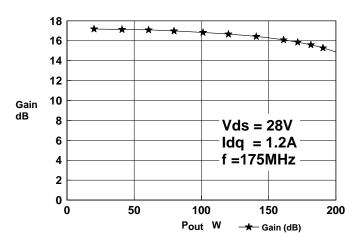


Figure 1. Gain vs. Output Power

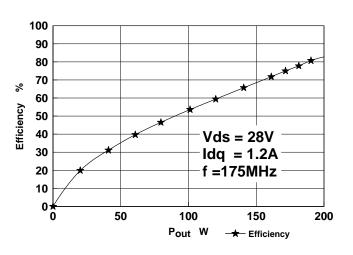


Figure 2. Efficiency vs. Output Power

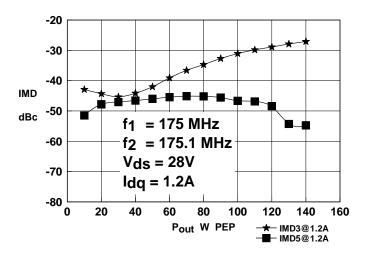


Figure 3. IMD vs Output Power

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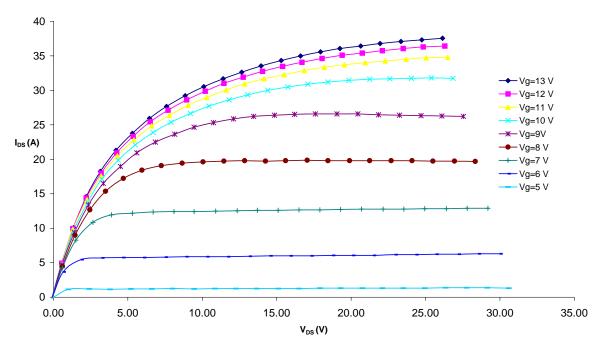


Figure 4 - Typical IV Characteristics.

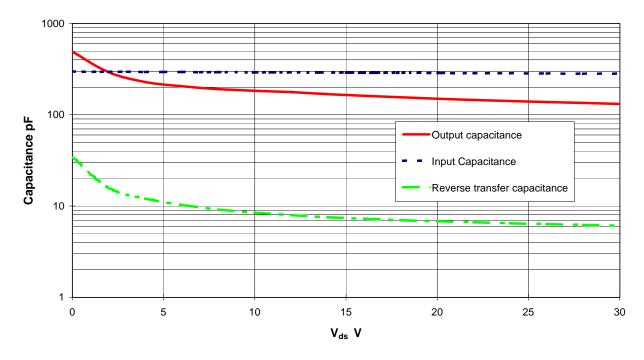


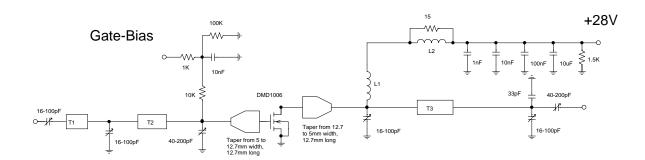
Figure 5 - Typical CV Characteristics.

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## 175 MHz Test Fixture

Substrate 1.6mm PTFE/glass, Er = 2.5 All microstrip lines W = 5mm

- T1 7.5mm
- T2 16mm
- T3 20mm
- L1 9 turns 20swg encamelled copper wire, 6mm i.d.
- L2 11 turns 19swg enamelled copper wire on Fair-Rite FT82 ferrite core

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